

	01Sept.(Mon)	02Sept.(Tue)	03Sept.(Wed)	04Sept.(Thu)	05Sept.(Fri)	
9:00-9:15		Opening	[Wed-I-1A] K. Kushiya : High efficiency and large volume production of CIS-based modules	[Thu-I-1A] S.-H. Wei : First-principles design of multinary compounds for energy applications	[Fri-I-1A] M. Ishii : Selective atomic-scale-evaluation of luminescent rare-earth dopants: Site-selective x-ray absorption fine structure using x-ray excited optical luminescence (XEOL-XAFS)	
9:15-9:30		[Tue-I-1A] M. Yamaguchi : Fundamentals and R&D Status of III-V Compound Solar Cells and Materials				
9:30-9:45			[Wed-O-1A] C. Pettenkofer : From band structure to band alignment- a study on chalcopyrite surfaces	[Thu-I-2A] S. Schorr : Point defect characteristics of quaternary compound semiconductors	[Fri-I-2A] D. Poelman : Persistent luminescence: materials and applications	
9:45-10:00		[Tue-I-2A] H. Hosono : Hydrogen-bearing iron-based superconductors	[Wed-O-2A] G. Gurieva : Structural characterisation of $Cu_2ZnSn(S_{1-x}Se_x)_4$	[Thu-I-3A] R. Scheer : Insights into thin film chalcopyrite/kesterite growth and solar cells from real time XRD	[Fri-I-3A] N. Mamedov : $TiMeX_2$: Band Structure, Optical Properties and Application	
10:00-10:15			[Wed-O-3A] K. Furuta : Improvement of $Cu_2ZnSn(S,Se)_4$ solar cell efficiency by surface treatment			
10:15-10:30		Break	Break	Break	Break	
10:30-10:50						
10:50-11:05		[Tue-I-3A] C. Heske : Using soft x-rays and electrons to determine the electronic structure of multinary semiconductors for solar energy conversion	[Wed-I-2A] I. M. Tiginyanu : Nanostructuring of Semiconductor Compounds by Design	[Thu-O-1A] T. Maeda : First-principles study on alkali-metal effect of Li, Na, and K in Cu_2ZnSnS_4 and $Cu_2ZnSnSe_4$	[Fri-O-1A] H. Kawaguchi : Red emitting conductive $CuAlS_2$:Mn, Si thin films	
11:05-11:20				[Thu-O-2A] T. Nishimura : Fabrication of $Cu(In,Ga)Se_2$ solar cells with a single graded band profile	[Fri-O-2A] H. Anzai : Relation between the nodal and antinodal gap and critical temperature in high-Tc superconductor $Bi_2Sr_2CaCu_2O_{8-\delta}$	
11:20-11:35		[Tue-I-4A] R. Agrawal : Nanoparticle Ink Based Route for Thin Film Solar Cells of Quaternary Chalcogenides	[Wed-I-3A] T. Arima : Toward the electric-field control of magnetization in matter	[Thu-O-3A] T. Fukuyama : Surface electronic structure of CIGS films grown on polymer substrate	[Fri-O-3A] K. Yamasaki : Thermally induced spin injection in Co_2FeSi :Cu lateral spin-valve devices	
11:35-11:50				[Thu-O-4A] J. Y. Kim : Fabrication of a $Cu_2ZnSnSe_4$ thin film solar cell with 7.3 % efficiency from a sputtered metallic precursor without using a toxic H_2Se gas atmosphere	[Fri-O-4A] K. Mimura : Hard X-Ray Photoemission Study of $EuNi_2X_2$ (X = Si, P, Ge): Relation between Eu Mean Valence and Eu 3d Spectral Shape	
11:50-12:05		[Tue-I-5A] N. Elkins-Daukes : Nanostructured electronic and optical materials for high efficiency solar cells	[Wed-I-4A] Y. Sutou : Phase change characteristics of Cu-Ge-Te ternary film and its application to PCRAM,	[Thu-O-5A] W. Gong : Crystallographic and optical properties of $(Cu, Ag)_2ZnSnS_4$ and $(Cu, Ag)_2ZnSnSe_4$ solid solutions	[Fri-I-4A] T. Araki : RF-MBE Growth of InN and InGaN Ternary Alloys Using DER1	
12:05-12:20				[Thu-O-6A] Z. Jehl : Characterization of narrow bandgap CIGSe under light concentration and tandem conditions		
12:20-14:00		Lunch	Lunch	Lunch	[Fri-I-5A] (12:20-12:50) J. Paier : Redox properties and reactivity of Au/ceria and VOx/ceria interfaces: Insights, pitfalls, and caveats born out of DFT (12:50-13:00) Closing	
14:00-14:15		[Tue-O-1A] S. Ikeda : Fabrication of Cu_2ZnSnS_4 Thin Films using Electrodeposited Metallic Precursors	[Tue-I-6B] R. J. Walters : High Efficiency PV Opportunities for Quantum Wells on InP	[Wed-O-4A] J. Chantana : Bismuth-Doped $Cu(In,Ga)Se_2$ Absorber Prepared by Multi-layer Precursor Method and Its	[Thu-O-7B] S.-W. Chang : Growth of amorphous Zn-Sn-O buffer layers deposited via RF magnetron sputtering for CIGS	
14:15-14:30		[Tue-O-2A] T. Yamamoto : Improvement of $In_2S_3/ZnCuInS_2$ interfaces for wide-gap solar cells	[Wed-O-5A] M. Yamazaki : Photoluminescence and Photoacoustic Study of $Cu(In,Ga)_2S_2$ Crystals	[Wed-O-5B] T. Ishinaga : Luminescent Property and Mechanism of $ZnAl_2O_4$ Ultra Violet Emitting Phosphor	[Thu-O-8B] T. Washio : Optimization of Sulfurization Condition of CZTS Thin Films by TG/DTA	
14:30-14:45		[Tue-O-3A] A. Kanai : Annealing temperature dependence of photovoltaic properties of solar cells containing Cu_2SnS_3 thin	[Tue-O-3B] T. Ohshima : In-situ Observation of Radiation Degradation of GaAs Solar Cells with InGaAs Quantum Dot	[Wed-O-6A] H.-C. Wu : High performance IGZO thin film transistors with optimized IGZO composition structure using	[Thu-O-9B] N. Tsuboi : $CuInS_2$ films by reactive-sputtering method with Cu and In targets for metal-sources and H_2S or	
14:45-15:00		Break	Break	Break	[Thu-O-10B] R. Mantoku : Cu_2SnS_3 films prepared by reactive-sputtering alternately Cu and Sn targets under Ar-	
15:00-15:15	Tutorials on "Recent Status of Multinary Compounds Solar Cells and Related Characterization Techniques (in Japanese)", organized by "Professional Group of Multinary Compounds and Solar Cells" in JSAP.	Symposium I "Any new photovoltaic materials superior to CIGS?"	[Tue-I-7B] T. Takamoto : Improvement on High efficiency Multi-junction Solar Cells	Symposium II "Advanced characterization of solar cells" [Wed-S-1A] S. Shirakata : Introductory Talk [Wed-S-2A] M. Okano : Photocarrier dynamics in CIGS, CZTS and related materials revealed by ultrafast optical spectroscopy	[Thu-O-11B] T. Hamada : Effect of sintering time on uniformity of electrodeposited Cu_2ZnSnS_4 thin films studied	
15:15-15:30		[Tue-S-1A] R. Scheer : A unique material? - Historic achievements of CIGS research	[Tue-O-4B] O. Alexperov : Temperature Dependent Spectroscopic Ellipsometry of Ag_2Se and Ag_2S with Phase	[Wed-S-3A] T. Takahashi (Univ. Tokyo): Photo-assisted scanning probe microscopy on CIGS solar cells	[Thu-O-12B] D. Kawade : Fabrication of visible-light transparent solar cells composed of $NiO/Ni_{1-x}Zn_xO/ZnO$	
15:30-15:45		[Tue-S-2A] H. Katagiri : Recent progress and future aspects of CZTS solar cells	[Tue-O-5B] H. Sato : Electronic Structure of $YbNiX_3$ (X=Si, Ge) Studied by Hard X-Ray Photoemission Spectroscopy	[Wed-S-4A] S. Kawakita : Radiation-induced defects in CIGS films		
15:45-16:00		[Tue-S-3A] T. Minemoto : Development of chalcogenide compound semiconductors for solar cell applications	[Tue-O-6B] N. Hoppo : Local Structure Analysis of Fuel Cell Electrolyte Material YSZ by X-ray Fluorescence Holography			
16:00-16:15			[Tue-O-7B] S. Hosokawa : Structural studies on $TlInSe_2$ thermoelectric material by x-ray diffraction, XAFS, and x-ray			
16:15-16:30			Break	Break		
16:30-16:45						
16:45-17:00			[Tue-O-8B] Y. Maeda : Fabrication of transparent $Cu_xZn_{1-x}S/ZnS$ heterojunction diodes by photochemical	Symposium II "Advanced characterization of solar cells" [Wed-S-5A] T. Maeda : First Principles insights on characteristics of $CuInSe_2$ and Cu_2ZnSnS_4 based photovoltaic semiconductors	[Wed-O-13B] T. Ito : Detection of magnetic domains of multiferroic $BiFeO_3$ single crystals with single ferroelectric	
17:00-17:15		Welcome reception	Symposium I "Any new photovoltaic materials superior to CIGS?"	[Tue-O-9B] T. Okamoto : Deposition of Cl-doped CdTe Polycrystalline Films by Close-Spaced Sublimation	[Wed-O-14B] K. Hayashi : Pyroelectric Energy Harvesting Using $BaTiO_3$ Compounds	[Wed-O-15B] A. M. Kerimova : Metallic conductivity and weak antilocalization in $Bi_2Te_3/Se_{0.3}$ thin films
17:15-17:30			[Tue-S-4A] A. Wakamiya : Recent progress of perovskite solar cells	[Tue-O-10B] A. Uruno : The Growth of $AgGaTe_2$ layers on glass substrates with Ag_2Te buffer layer by closed space	[Wed-S-6A] S. Shirakata : Photoluminescence characterization of recombination process in CIGS thin films and solar cells	[Wed-O-16B] S. Maensiri : Structure, and Magnetic Properties of Monodisperse Ni-doped Co_2 Nanospheres
17:30-17:45	[Tue-S-5A] N. Terada : Characterization of materials for solar cells by direct and inverse photoemission spectroscopy		[Tue-O-11B] J. Rame : Chemical synthesis and crystal growth of $AgGaGeS_2$, a material for mid-IR nonlinear laser	[Wed-S-7A] A. Yamada : Concluding Remarks	[Wed-O-17B] M. Ishikawa : First-principles study of doping properties in $ZnSnAs_2$	
17:45-18:00	[Tue-S-6A] T. Sakurai : Electrical and optical characterization of compound semiconductors for solar cells		[Tue-O-12B] A. Ashida : Electrical Properties of Cu_2O Thin Films Prepared by Electrochemical Process		[Wed-O-18B] T. Arslanov : Pressure-induced Unconventional Behavior of Ferromagnetically MnP Clusters in Strongly	
18:00-18:15		[Tue-O-13B] T. Suzuki : Epitaxial Growth of a Chromium Nitride Thin Films with Addition of Silicon				
18:15-18:30		Break	Break			
18:30-18:45						
18:45-19:00						
19:00-19:15		poster 1	poster 2			
19:15-19:30		odd number of poster numbers	even number of poster numbers			
19:30-19:45				Banquet		
19:45-20:00						